

Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

DESCRIPTION

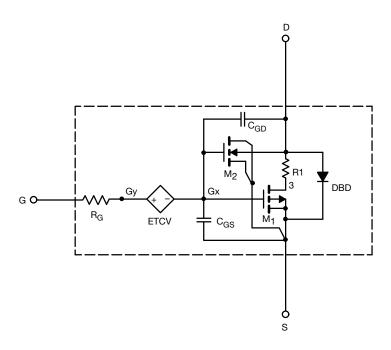
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}$ C to + $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si7157DP

Vishay Siliconix

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	0.90	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 25 A	0.00123	0.00125	Ω
		V _{GS} = - 4.5 V, I _D = - 20 A	0.00159	0.00155	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 25 A	140	120	S
Diode Forward Voltage	V _{SD}	I _S = - 5 A	- 0.64	- 0.64	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 10 V, V _{GS} = 0 V, f = 1 MHz	20 300	22 000	pF
Output Capacitance	C _{oss}		2690	2470	
Reverse Transfer Capacitance	C _{rss}		2670	2515	
Total Gate Charge	0	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	332	415	nC
	Q_g	V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 20 A	176	202.5	
Gate-Source Charge	Q _{gs}		32.5	32.5	
Gate-Drain Charge	Q _{gd}		51.5	51.5	

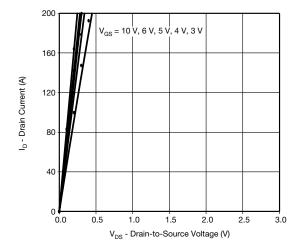
Note

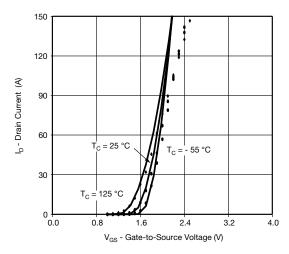
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

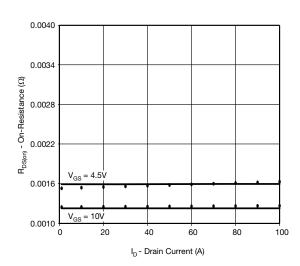
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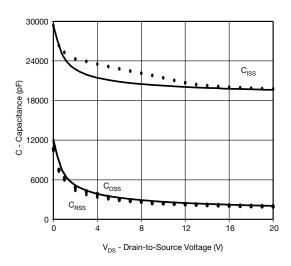
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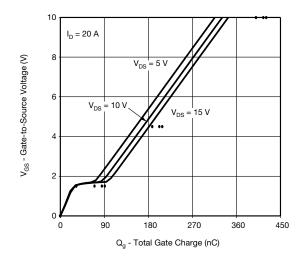
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)

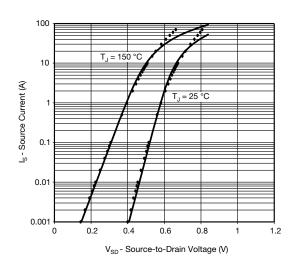












Note

• Dots and squares represent measured data.



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